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PATENT
2804-0102P

#4/A
7-12-01
A Jones

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: MORISHITA, Takashi et al. Conf.:
Int'l. Appl. No.: PCT/JP99/05231
Appl. No.: New Group:
Filed: March 23, 2001 Examiner:
For: SEMICONDUCTOR SUBSTRATE AND PRODUCTION METHOD
THEREOF, SEMICONDUCTOR DEVICE USING THE SAME
AND PRODUCTION METHOD THEREOF

PRELIMINARY AMENDMENT

BOX PATENT APPLICATION

Assistant Commissioner for Patents
Washington, DC 20231

March 23, 2001

Sir:

The following Preliminary Amendments and Remarks are respectfully submitted in connection with the above-identified application.

AMENDMENTS

IN THE SPECIFICATION:

Please amend the specification as follows:

Before line 1, insert --This application is the national
phase under 35 U.S.C. § 371 of PCT International Application No.
PCT/JP99/05231 which has an International filing date of
September 24, 1999, which designated the United States of
America.--